



# Selective Gas Detection of SnO<sub>2</sub>-TiO<sub>2</sub> Gas Sensors

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**Abstract.** The composite, consisting of two materials with different sensing temperatures, may show the selectivity for a particular gas. In this study, the microstructural and compositional effects on the electrical conductivity and the CO and the H<sub>2</sub> gas sensing properties of SnO<sub>2</sub>-TiO<sub>2</sub> composites were examined. SnO<sub>2</sub>-TiO<sub>2</sub> composites in entire (0–100 mol%) composition range were fabricated in the form of porous pellet by sintering at 800°C for 3 h. The effects of CuO-coating (or doping) on the electrical conductivity and the sensing properties to 200 ppm CO and H<sub>2</sub> gases were examined.

With CuO-coating, SnO<sub>2</sub>-TiO<sub>2</sub> composites showed the increased sensitivity to CO gas and a large difference in the sensing temperatures between CO and H<sub>2</sub> gases. As a result, CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites showed the selectivity for CO gas between 100°C and 190°C and the selectivity for H<sub>2</sub> gas between 280°C and 380°C.

**Keywords:** SnO<sub>2</sub>, TiO<sub>2</sub>, CuO, composite, sensitivity, selectivity

## 1. Introduction

Semiconductor gas sensors have been researched for several decades owing to their advantages such as the low cost of fabrication, the high sensitivity, and the possibility of miniaturization and integration. *N*-type semiconductor materials such as SnO<sub>2</sub>, ZnO, Fe<sub>2</sub>O<sub>3</sub>, and In<sub>2</sub>O<sub>3</sub> have been used for the detection of inflammable or toxic gases such as NO<sub>x</sub>, CH<sub>4</sub>, or CO [1]. In order to improve the gas sensing properties of the sensors, many studies have been focused on the use of the noble metal catalysts [2] or the heterogeneous interface [3, 4]. However, they still lack the gas selectivity.

We have previously reported that SnO<sub>2</sub>-ZnO [5] and SnO<sub>2</sub>-Zn<sub>2</sub>SnO<sub>4</sub> [6] composites coated with CuO showed the high selectivity to CO and H<sub>2</sub> gases at low and high temperatures, respectively. When the sensing materials are the composite of two phases that show good sensitivities at low (e.g., SnO<sub>2</sub>) and high (e.g., ZnO or Zn<sub>2</sub>SnO<sub>4</sub>) temperature, respectively, the selective detection between CO and H<sub>2</sub> gases can be made. SnO<sub>2</sub>-TiO<sub>2</sub> composites may be another candidate for the material with high CO selectivity due to the dif-

ference in sensing temperatures for SnO<sub>2</sub> (~350°C) [7] and TiO<sub>2</sub> (above 400°C) [8, 9]. Thus, in this study, the electrical conductivity and the sensing properties of uncoated SnO<sub>2</sub>-TiO<sub>2</sub> composites and CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites to reducing gases (200 ppm CO and H<sub>2</sub> gases) were examined between 70°C and 560°C. The microstructural and compositional effects on the gas sensing properties, especially on the temperature ( $T_{MAX}$ ) showing the maximum sensitivity values ( $S_{MAX}$ ), were discussed.

## 2. Experimental Procedure

Appropriate amount of tin oxide powder (99.9%, Aldrich, USA) and titanium oxide powder (99.9%, anatase, Aldrich, USA) were mixed by ball milling in ethanol for 12 h. The slurry was filtered and dried. The mixed powders were uniaxially pressed into pellets and subsequently cold-isostatically pressed at 200 MPa. The pellets were sintered at 800°C for 3 h in air. The sintered densities of samples were measured by the Archimedeian method. The phase and the microstructure were characterized by X-ray diffractometry

(XRD, MAC Science, M18XCE, JAPAN) and field-emission scanning-electron microscopy (FE-SEM, Hitachi, S-4200, JAPAN), respectively. The surface area of porous sintered pellet was determined by BET surface-area analyzer (Micromeritics, ASAP2010, USA).

For the CuO-coating, the sintered samples were dipped for 1 h in 1wt% CuO solution prepared by Pechini method [10]. The samples impregnated with CuO-solution were heated to 350°C for 2 h followed by firing at 750°C for 3 h. Provided that the pore of the samples was fully filled with the solution, the CuO content can be estimated as ~0.2 mol% after firing. We found that the Cu was distributed homogeneously throughout the whole sample with CuO coating by using EPMA. Although the samples were coated with CuO, the effect of coating was previously found to be the same as the electrical doping [6]. Thus we have used the terms “coating” and “doping” interchangeably. Since CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites were merely coated with CuO, the phase and the microstructure of the samples were expected to be unchanged from these of uncoated SnO<sub>2</sub>-TiO<sub>2</sub> composite. Thus, we will refer the data of uncoated SnO<sub>2</sub>-TiO<sub>2</sub> composite in the discussion related the microstructure information of CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites.

For the measurement of electrical conductivity, the flat surfaces of the samples were painted with Pt paste (Engelhard model #6082, fluxed, USA) followed by firing at 600°C for 30 min. In order to exclude the moisture effect during the measurement procedure, the samples in a quartz tube were heated up to 560°C (uncoated system) or 440°C (coated system) in air and then cooled to the measurement temperature. The I-V characteristics were measured by using high-voltage source/measure unit (Keithley, K237, USA) after equilibrating the samples in air for 60 min. The applied voltage was varied from -10 to +10 volts. The current was measured 2 seconds after applying the voltage. The samples were kept in air for 30 min before changing the measurement temperature. The electrical measurement was repeated after flowing CO or H<sub>2</sub> gas, 200 ppm balanced by air, for 20 min at 100 cm<sup>3</sup>/min rate. In order to eliminate the complication due to the water vapor effect, the relative humidity was fixed to 23% at 25°C by flowing the gases through the MgCl<sub>2</sub>-saturated solution [11]. Gas sensitivity was defined as  $R_{Air}/R_{Gas}$ , where  $R_{Air}$  and  $R_{Gas}$  denote the electrical resistance values in air and in sample gas, respectively.

### 3. Results and Discussion

#### 3.1. Phase and Microstructure

Figure 1 shows XRD patterns of SnO<sub>2</sub>, ST10, ST99, and TiO<sub>2</sub> samples, sintered at 800°C for 3 h. The numbers in the sample notation represent TiO<sub>2</sub> mole fraction, for example, ST10 means 90 mol% SnO<sub>2</sub>-10 mol% TiO<sub>2</sub> sample. Although the SnO<sub>2</sub>-TiO<sub>2</sub> system have the subsolidus miscibility gap [12], the crystal structures of SnO<sub>2</sub> and TiO<sub>2</sub> are the same, i.e., rutile. Thus the solubility limit of TiO<sub>2</sub> into SnO<sub>2</sub> and SnO<sub>2</sub> into TiO<sub>2</sub>, respectively, was expected to be more than 10 mol% when sintered at 800°C. However, as shown by the small SnO<sub>2</sub> peaks in ST99 specimen, the solubility of SnO<sub>2</sub> into TiO<sub>2</sub> is estimated to be less than 1 mol% for the present study. On the other hand, TiO<sub>2</sub> peaks start to show up when more than 10 mol% TiO<sub>2</sub> was added into SnO<sub>2</sub>. For the estimation of solubility limit of TiO<sub>2</sub> into SnO<sub>2</sub>, the lattice parameters of SnO<sub>2</sub>-rich phases were examined as shown in Fig. 2. As TiO<sub>2</sub> content increased, the lattice parameters of SnO<sub>2</sub>-rich phases slightly decreased. However the decrease was

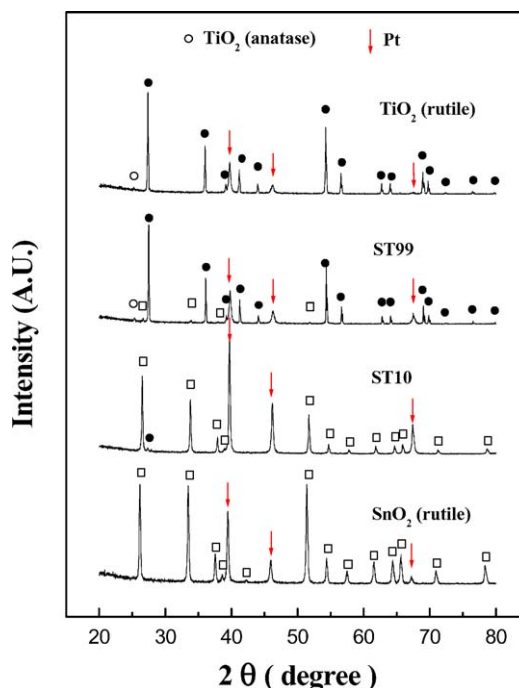


Fig. 1. XRD patterns of SnO<sub>2</sub>, ST10, ST99, and TiO<sub>2</sub> samples sintered at 800°C for 3 h. Pt is reference phase for peak calibration.

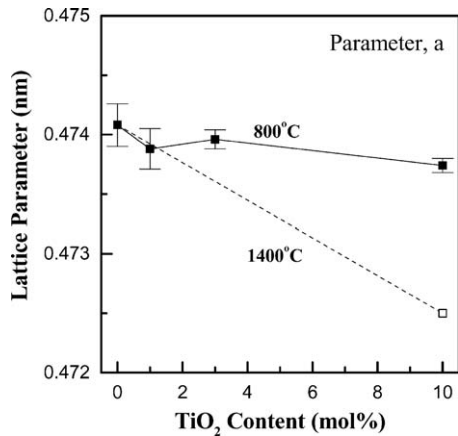


Fig. 2. The variation of lattice parameter *a* in SnO<sub>2</sub>-rich phases. The solid line is for the samples sintered at 800°C for 3 h. The dashed line is the one expected for the powder calcined at 1400°C for 3 h.

very small compared with that of ST10 powder calcined at 1400°C for 3 h (dashed lines). In this study, to examine the equilibrium solubility, samples were also sintered at 1400°C. Samples sintered at 1400°C

showed no second phase. Thus, the solubility of TiO<sub>2</sub> into porous SnO<sub>2</sub> at 800°C is estimated to be less than 2 mol% from this observation and SnO<sub>2</sub> and TiO<sub>2</sub> forms a mixture. This small solubility coincides with another phase diagram for SnO<sub>2</sub>-TiO<sub>2</sub> shown by Garcia and Speidel [13] which shows very limited solubility of TiO<sub>2</sub> in SnO<sub>2</sub>.

The fractured surfaces of the SnO<sub>2</sub>-TiO<sub>2</sub> composite samples were shown in Fig. 3. All samples showed the relative sintered density of 60–65%. SnO<sub>2</sub> has much smaller particle size (<0.1 μm) than that of TiO<sub>2</sub> (~0.5 μm). As TiO<sub>2</sub> content increases in the composite, large TiO<sub>2</sub> particles start to show up. Up to 30 mol% TiO<sub>2</sub> content, the BET surface area of the samples increased from ~4.5 (SnO<sub>2</sub>) to ~6.9 m<sup>2</sup>/g (ST30). However, with further TiO<sub>2</sub> addition, the surface area of the composites continuously decreased. The maximum value of the surface area shown for ST30 sample is due possibly to the breakdown of agglomerated SnO<sub>2</sub> particles by TiO<sub>2</sub>. Thus SnO<sub>2</sub> particles cover the surface of large TiO<sub>2</sub> particle as shown in Fig. 3.

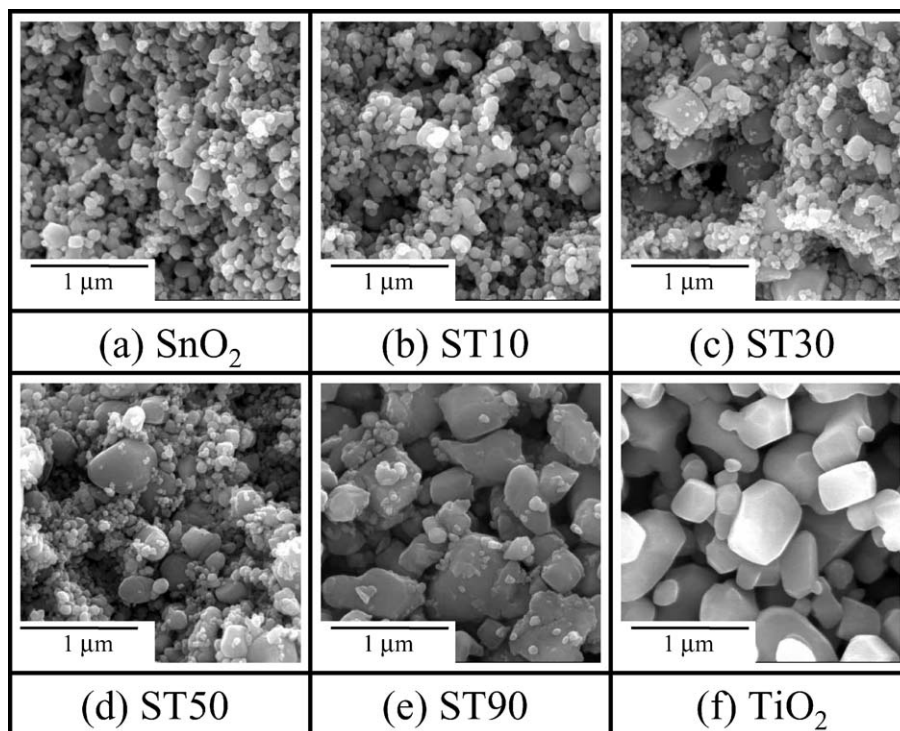


Fig. 3. FE-SEM micrographs of fractured surface of (a) SnO<sub>2</sub> (b) ST10, (c) ST30, (d) ST50, (e) ST90, and (f) TiO<sub>2</sub> samples.

### 3.2. Electrical and Gas Sensing Properties of Uncoated SnO<sub>2</sub>-TiO<sub>2</sub> Composites

Figure 4 shows the electrical conductivity of SnO<sub>2</sub>, TiO<sub>2</sub>, and SnO<sub>2</sub>-TiO<sub>2</sub> composites without Cu coating, plotted versus inverse of temperature in air (23% R.H.). All the samples examined in this study showed the nearly linear current-voltage (I-V) curves both in air and in reducing gases (200 ppm CO and 200 ppm H<sub>2</sub>) and thus the electrical conductivity was calculated from the slope of I-V curve. SnO<sub>2</sub> showed the highest conductivity ( $10^{-2.5}$ – $10^{-4}$  S/cm) among all samples. The electrical conductivity of SnO<sub>2</sub> continuously decreased with the increasing amount of TiO<sub>2</sub>. Above 70 mol% TiO<sub>2</sub>, the conductive values were mostly determined by the resistive TiO<sub>2</sub> phase. The conductive SnO<sub>2</sub>-phase percolates the resistive TiO<sub>2</sub> matrix phase above ~30 mol% SnO<sub>2</sub>. TiO<sub>2</sub>-rich samples showed the conductivity minima at ~360°C due to the adsorption of water vapor. Water vapors are adsorbed with decreasing temperature.

Figure 5 shows the temperature dependence of the sensitivity of SnO<sub>2</sub>, TiO<sub>2</sub>, and SnO<sub>2</sub>-TiO<sub>2</sub> composites to (a) 200 ppm CO and (b) 200 ppm H<sub>2</sub> gases. Note that the y-axis scales are different. SnO<sub>2</sub> showed the highest sensitivity value (~4) to CO gas at ~345°C. The addition of 10 mol% TiO<sub>2</sub> decreased the temperature showing the maximum sensitivity ( $T_{MAX}$ ) for

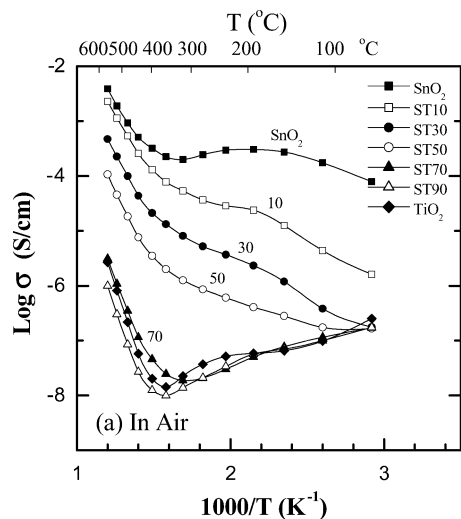


Fig. 4. Electrical conductivity of SnO<sub>2</sub>, TiO<sub>2</sub>, and uncoated SnO<sub>2</sub>-TiO<sub>2</sub> composites in air (23% R.H.) plotted versus temperature. The numbers were included to help to identify the TiO<sub>2</sub> content.

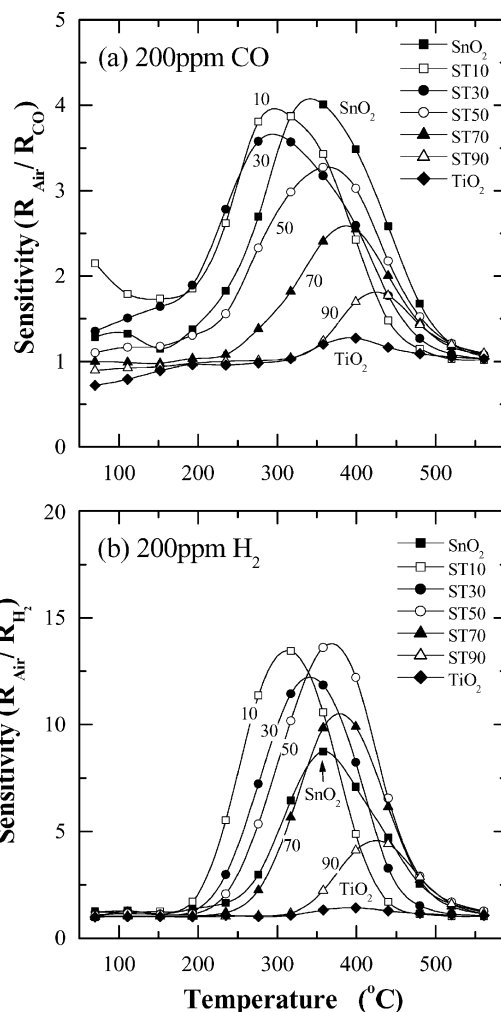


Fig. 5. Temperature dependence of the sensitivity to (a) 200 ppm CO and (b) 200 ppm H<sub>2</sub> gases of SnO<sub>2</sub>, TiO<sub>2</sub>, and uncoated SnO<sub>2</sub>-TiO<sub>2</sub> composites.

CO gas as much as ~50°C from ~345 to ~295°C as shown in Fig. 5(a). However, the maximum sensitivity value ( $S_{MAX}$ ) of ST10 sample to CO gas was not changed from that of SnO<sub>2</sub>. Further addition of TiO<sub>2</sub> continuously decreased  $S_{MAX}$  to CO gas and shifted  $T_{MAX}$  toward higher temperature. Similarly, the  $T_{MAX}$  value of SnO<sub>2</sub> for H<sub>2</sub> gas also decreased as much as ~40°C from ~355 to ~315°C when 10 mol% TiO<sub>2</sub> was added as shown in Fig. 5(b) and then continuously increased above 10 mol% TiO<sub>2</sub>. However, the  $S_{MAX}$  value to H<sub>2</sub> gas was much higher than that to CO gas. ST90 sample showed the maximum sensitivity values at ~430°C for both CO and H<sub>2</sub> gases. Thus it is evident

that TiO<sub>2</sub>-rich phases have the higher  $T_{MAX}$  than that of SnO<sub>2</sub>. The  $S_{MAX}$  of TiO<sub>2</sub> sample to both CO and H<sub>2</sub> gases showed less than 1.5 at  $\sim 400^\circ\text{C}$  due to the large particle size ( $\sim 0.5 \mu\text{m}$ ). From the microstructural information shown in Fig. 3, the samples with composition between ST10 and ST50 were expected to show good sensitivity to reducing gases due to their fine particle sizes. The expectation was met in this study.

### 3.3. Electrical and Gas Sensing Properties of CuO-Coated SnO<sub>2</sub>-TiO<sub>2</sub> Composites

Figure 6 shows the electrical conductivity of uncoated SnO<sub>2</sub>, CuO-coated SnO<sub>2</sub> (SnO<sub>2</sub>C) and TiO<sub>2</sub> (TiO<sub>2</sub>C), and CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites, plotted versus inverse of temperature in air (23% R.H.). The numbers in the sample notation represent TiO<sub>2</sub> mole fraction and 'C' indicates CuO-coating. For example, ST30C means 70 mol% SnO<sub>2</sub>-30 mol% TiO<sub>2</sub> and CuO coated sample. In the previous section, Uncoated SnO<sub>2</sub> showed the highest conductivity ( $10^{-4.1}$ – $10^{-3.3}$  S/cm) among all samples between 70 and 440°C. The electrical conductivity of SnO<sub>2</sub> drastically decreased with CuO coating, 1–4 orders of magnitude, depending upon temper-

ature. In order to explain the reduced conductivity, the change of charge carriers in the bulk phase and surface should be considered. Since the particle size is not changed with CuO coating, the conductivity decrease is ascribed to the doping effect. When Cu<sup>2+</sup> substitutes Sn<sup>4+</sup>, the hole concentration increases and the conductivity of *n*-type SnO<sub>2</sub> decreases [7]. Thus, the reduced conductivity at high temperature, where the amount of the adsorbed oxygen ions is negligible, can be explained by doping effect. The CuO coated on the surface of SnO<sub>2</sub> particles may also boost oxygen adsorption, thus decreasing the conductivity of SnO<sub>2</sub>. The electrical conductivity of composite continuously decreased with the increasing amount of TiO<sub>2</sub> due to the highly resistive TiO<sub>2</sub> phase. The CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites showed approximately two orders of magnitude lower electrical conductivity than those for undoped SnO<sub>2</sub>-TiO<sub>2</sub> composites.

Figure 7 shows the temperature dependence of the sensitivity of uncoated SnO<sub>2</sub>, SnO<sub>2</sub>C, TiO<sub>2</sub>C, and CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites to (a) 200 ppm CO and (b) 200 ppm H<sub>2</sub> gases. Note that the y-axis scales are different. The uncoated SnO<sub>2</sub> showed the maximum sensitivity ( $\sim 4$ ) to CO gas at  $\sim 345^\circ\text{C}$ . With CuO coating or doping, the temperature showing the maximum sensitivity ( $T_{MAX}$ ) for CO gas decreased from  $\sim 345$  to  $\sim 255^\circ\text{C}$  and the maximum sensitivity value ( $S_{MAX}$ ) to CO gas increased from  $\sim 4$  to  $\sim 8$ . The  $T_{MAX}$  value of SnO<sub>2</sub>C for H<sub>2</sub> gas also decreased from  $\sim 355$  to  $\sim 270^\circ\text{C}$  with CuO coating as shown in Fig. 7(b). For SnO<sub>2</sub>, the increase of  $S_{MAX}$  to H<sub>2</sub> gas due to CuO coating is much less in ratio than  $S_{MAX}$  to CO gas. We have previously reported that the addition of CuO also lowers  $T_{MAX}$  of ZnO [14] and SnO<sub>2</sub> [5]. CuO apparently acted as a catalyst and thus lowered  $T_{MAX}$  for CO and H<sub>2</sub> gases. Although SnO<sub>2</sub>C showed the remarkably increased sensitivity only to CO gas, the difference in  $T_{MAX}$  to both gases was small. Thus, a low selectivity for CO gas was expected. The sensitivity values of TiO<sub>2</sub>C sample to either CO or H<sub>2</sub> gas were less than 1.5 due to its large particle size. The sensitivity value of CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites to CO gas did not change appreciably until TiO<sub>2</sub> was added above 50 mol%. In the previous section, when TiO<sub>2</sub> was added into SnO<sub>2</sub>, the  $S_{MAX}$  to CO gas continuously decreased with TiO<sub>2</sub> content. For H<sub>2</sub> gas, the sensitivity value almost doubled from  $\sim 9.9$  to  $\sim 18.3$  when 30 mol% TiO<sub>2</sub> was added into SnO<sub>2</sub>C. The increase of sensitivity value to H<sub>2</sub> gas was related to the increasing surface area with TiO<sub>2</sub> addition. Up to 50 mol% TiO<sub>2</sub>, the sensitivity

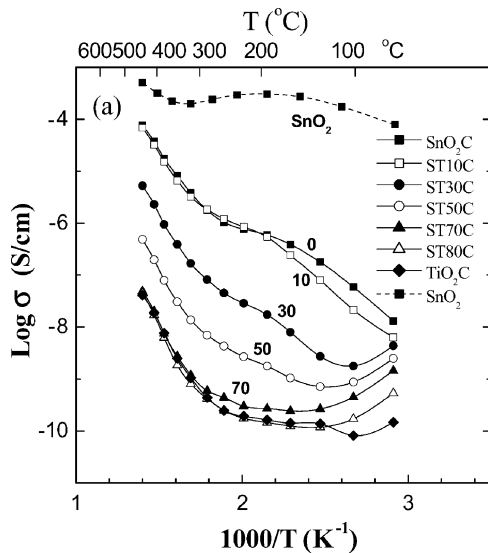


Fig. 6. Electrical conductivity of uncoated SnO<sub>2</sub>, SnO<sub>2</sub>C, TiO<sub>2</sub>C, and CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites in air (23% R.H.) plotted versus temperature. The numbers were included to help identifying the TiO<sub>2</sub> content.

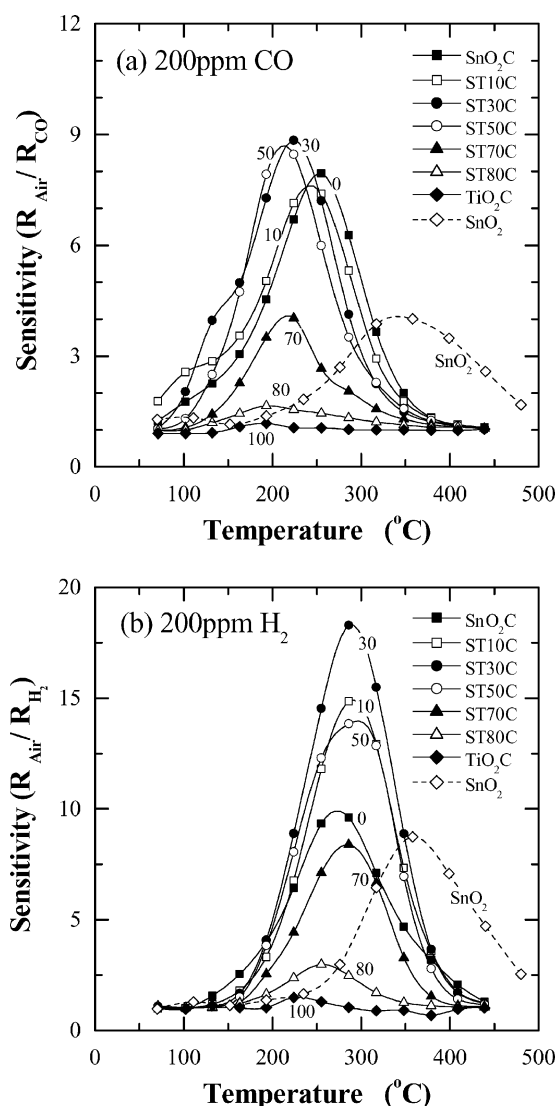


Fig. 7. Temperature dependence of the sensitivity to (a) 200 ppm CO and (b) 200 ppm H<sub>2</sub> gases of uncoated SnO<sub>2</sub>, SnO<sub>2</sub>C, TiO<sub>2</sub>C, and CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites.

to H<sub>2</sub> gas was relatively high. Above 70 mol% TiO<sub>2</sub>, the sensitivity value to H<sub>2</sub> gas decreased below that of SnO<sub>2</sub>C. Although the sensitivity value of CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites to CO gas increased twice with CuO coating, the sensitivity value to H<sub>2</sub> gas did not show appreciable change.

Figure 8 shows the selectivity of SnO<sub>2</sub>C and CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites for (a) CO gas against H<sub>2</sub> gas, defined as the ratio of the CO gas sensitivity to the H<sub>2</sub> gas sensitivity and (b) H<sub>2</sub> gas against CO gas.

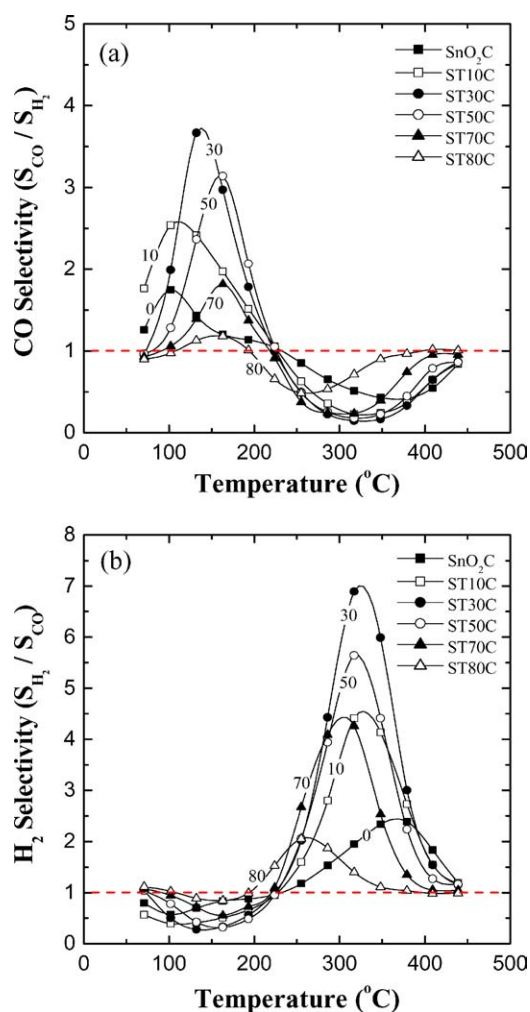


Fig. 8. (a) Temperature dependence of the CO-gas selectivity and (b) the H<sub>2</sub>-gas selectivity for CuO-coated SnO<sub>2</sub>-TiO<sub>2</sub> composites. The selectivity was defined as (a) the ratio of the CO sensitivity to the H<sub>2</sub> sensitivity or (b) vice versa.

Since the sensitivity value of TiO<sub>2</sub>C was very small to 200 ppm CO or H<sub>2</sub> gas, TiO<sub>2</sub>C sample was excluded in the selectivity curves. SnO<sub>2</sub>C showed a small selectivity value (~1.7) for CO gas at ~100°C. As TiO<sub>2</sub> content increased up to 30 mol%, the selectivity for CO gas gradually increased. As TiO<sub>2</sub> content further increased, however, the selectivity values decreased. Thus, ST30C composition showed the highest selectivity (~3.7 at ~130°C) for CO gas among all samples due to its high sensitivity to CO gas at low temperature, as shown in Fig. 7. Since all samples showed the higher sensitivity values to H<sub>2</sub> gas than that to CO gas at high

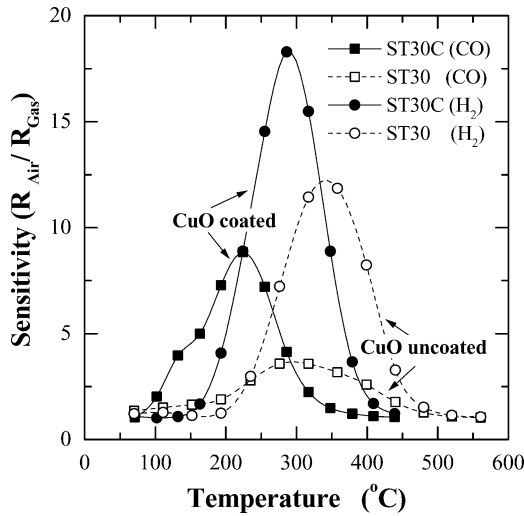


Fig. 9. Temperature dependence of the sensitivity of CuO-uncoated ST30 and CuO-coated ST30C to 200 ppm CO and 200 ppm H<sub>2</sub> gases.

temperature, the selectivity value for H<sub>2</sub> gas was nearly twice as high as that for CO gas for the same composition. Thus, ST30C composition also is the optimum composition for the selective detection of H<sub>2</sub> gas (~6.9 at ~315°C). The selectivity for CO gas was obtained in the temperature range between 100 and 190°C, however, the selectivity for H<sub>2</sub> gas was shown between 280 and 380°C, depending upon the TiO<sub>2</sub> content.

In order to show more clearly the effect of CuO coating for SnO<sub>2</sub>-TiO<sub>2</sub> composites, the sensitivity curves for CuO-uncoated ST30 and CuO-coated ST30C to 200 ppm CO and 200 ppm H<sub>2</sub> gases were compared (Fig. 9). ST30 sample showed the large difference (~45°C) in  $T_{MAX}$  between CO and H<sub>2</sub> gases due to the difference in sensing mechanism. With CuO coating, the  $T_{MAX}$  of ST30 for CO gas decreased from ~295 to 225°C and the  $S_{MAX}$  to CO gas increased from ~3.6 to ~8.8. Similarly, the  $T_{MAX}$  of ST30 for H<sub>2</sub> gas decreased from ~340 to ~285°C and the  $S_{MAX}$  increased from ~12.2 to ~18.3. However, the CuO-coating increases the  $S_{MAX}$  to CO gas more than that to H<sub>2</sub> gas and decreases the  $T_{MAX}$  for CO gas more than that for H<sub>2</sub> gas. Thus, ST30C shows large difference in the  $T_{MAX}$  values between CO and H<sub>2</sub> gases while keeping high  $S_{MAX}$  value. As a result, ST30C showed the highest selectivity for CO gas at relatively low temperature (~130°C)

and the highest selectivity for H<sub>2</sub> gas at relatively high temperature (~320°C), as shown in Fig. 8.

#### 4. Conclusions

From the observation of the XRD patterns and the variation of lattice parameters, SnO<sub>2</sub> and TiO<sub>2</sub> forms a mixture when sintered at 800°C. In the uncoated system, the sensitivity of composites to H<sub>2</sub> gas was higher than that of SnO<sub>2</sub> due to the increased surface area below 80% TiO<sub>2</sub> addition, however, the sensitivity to CO gas of uncoated composites decreased from that of SnO<sub>2</sub>.

The selectivity value of composite was modified with CuO coating and ST30C was found to be the optimum composition for the selective detection of either CO gas or H<sub>2</sub> gas. From the observation, the method to obtain the selective detection of CO gas was proposed. Controlling the temperature dependence of sensitivity value with composition and doping is a proposed method in this study.

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